

General Purpose NPN Epitaxial Planar Transistor

BTC4102S3

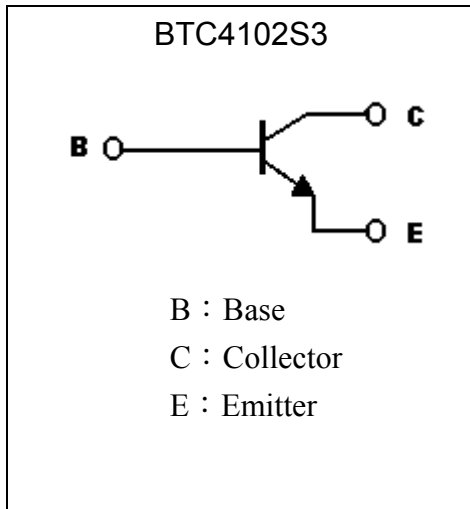
Description

The BTC4102S3 is designed for high voltage amplification application.

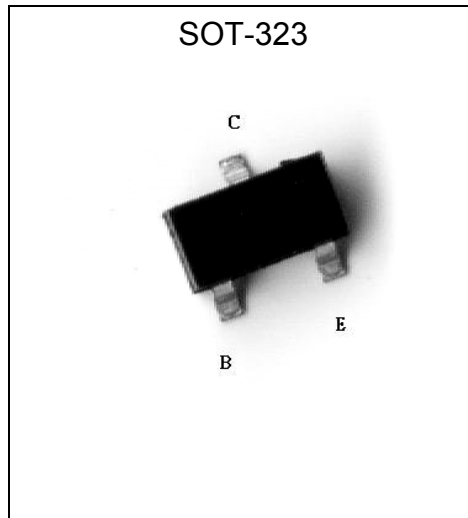
Features

- High breakdown voltage. ($BV_{CEO}=120V$)
- Complementary to BTA1579S3

Symbol



Outline



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CBO}	120	V
Collector-Emitter Voltage	V_{CEO}	120	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	50	mA
Power Dissipation	P_d	200	mW
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55~+150	°C



Characteristics (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CB0}	120	-	-	V	I _C =50μA
BV _{CEO}	120	-	-	V	I _C =1mA
BV _{EBO}	5	-	-	V	I _C =50μA
I _{CB0}	-	-	0.5	μA	V _{CB} =100V
I _{EBO}	-	-	0.5	μA	V _{EB} =4V
*V _{CE(sat)}	-	-	0.5	V	I _C =10mA, I _B =1mA
*h _{FE}	56	-	390	-	V _{CE} =6V, I _C =2mA
f _T	-	140	-	MHz	V _{CE} =12V, I _C =2mA, f=100MHz
Cob	-	2.5	-	pF	V _{CB} =12V, I _E =0A, f=1MHz

*Pulse Test : Pulse Width ≤380μs, Duty Cycle≤2%

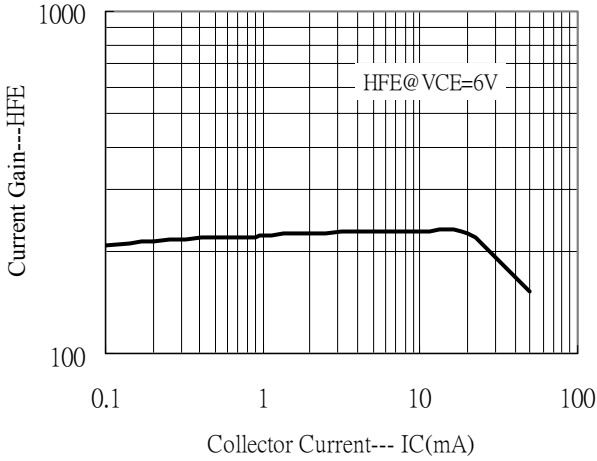
Classification Of h_{FE}

Rank	K	P	Q	R
Range	56~120	82~180	120~270	180~390

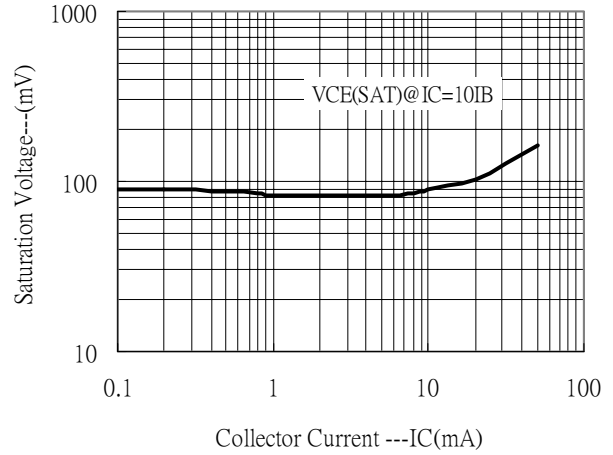


Characteristic Curves

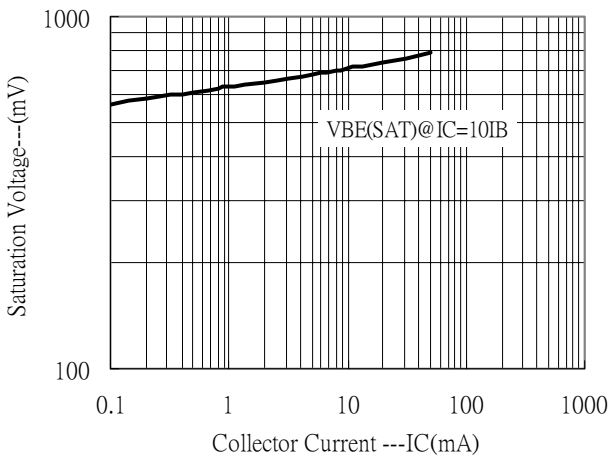
Current Gain vs Collector Current



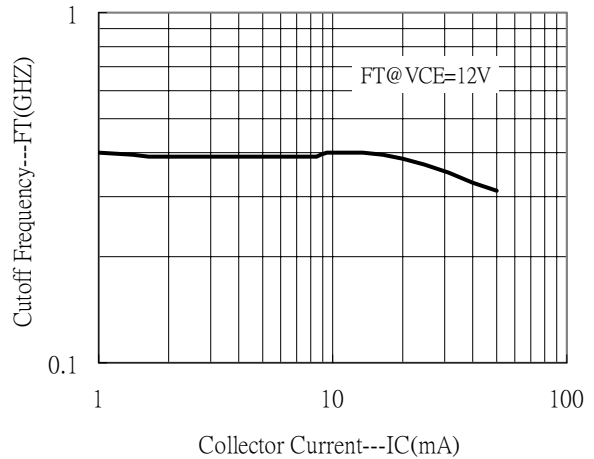
Saturation Voltage vs Collector Current



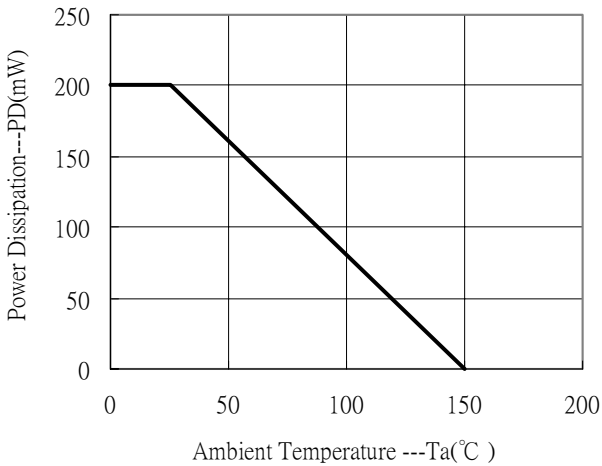
Saturation Voltage vs Collector Current



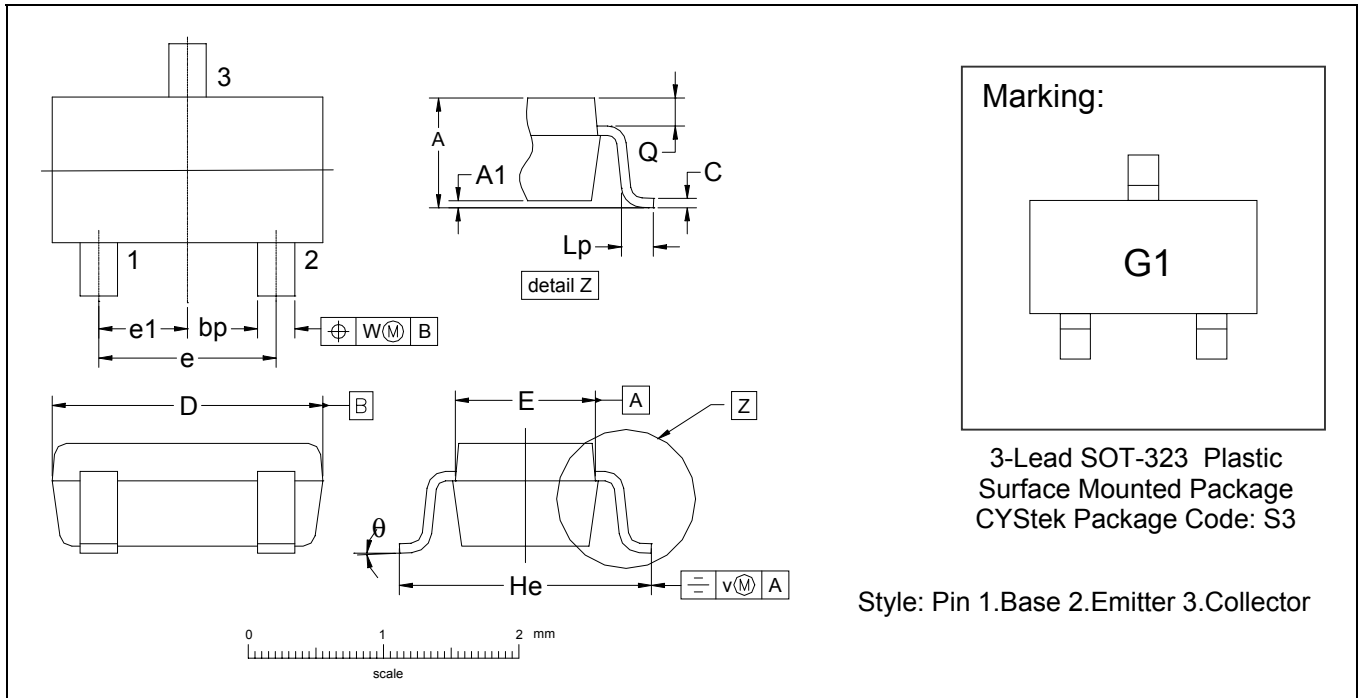
Cutoff Frequency vs Collector Current



Power Derating Curve



SOT-323 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.0315	0.0433	0.80	1.10	e1	0.0256	-	0.65	-
A1	0.0000	0.0039	0.00	0.10	He	0.0787	0.0886	2.00	2.25
bp	0.0118	0.0157	0.30	0.40	Lp	0.0059	0.0177	0.15	0.45
C	0.0039	0.0098	0.10	0.25	Q	0.0051	0.0091	0.13	0.23
D	0.0709	0.0866	1.80	2.20	v	0.0079	-	0.2	-
E	0.0453	0.0531	1.15	1.35	w	0.0079	-	0.2	-
e	0.0512	-	1.3	-	θ	-	-	10°	0°

Notes: 1.Controlling dimension: millimeters.
 2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.
 3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: 42 Alloy ; solder plating
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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